



Docket No.: M4065.0481/P481
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Glen Hush

Confirmation No. 2292

Application No.: 10/022,722

Group Art Unit: 2818

Filed: December 20, 2001

Examiner: H. Hoang

For: A PROGRAMMABLE CONDUCTOR
RANDOM ACCESS MEMORY AND A
METHOD FOR WRITING THERETO

INFORMATION DISCLOSURE STATEMENT (IDS)

Commissioner for Patents
Washington, DC 20231

Dear Sir:

Pursuant to 37 CFR 1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO/SB/08. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is filed more than three months after the U.S. filing date, OR more than three months after the date of entry of the national stage of a PCT application, AND after the mailing date of the first Office Action on the merits, whichever occurs first, but before the mailing date of a Final Rejection or Notice of Allowance.

A copy of each reference on PTO/SB/08 is attached.

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A concise explanation of relevance of the items listed on form PTO/SB/08 is:

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While the information and references disclosed in this Information Disclosure Statement may be "material" pursuant to 37 CFR 1.56, it is not intended to constitute an admission that any patent, publication or other information referred to therein is "prior art" for this invention unless specifically designated as such.

In accordance with 37 CFR 1.97(g), the filing of this Information Disclosure Statement shall not be construed to mean that a search has been made or that no other material information as defined in 37 CFR 1.56(a) exists. It is submitted that the Information Disclosure Statement is in compliance with 37 CFR 1.98 and the Examiner is respectfully requested to consider the listed references.

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Dated: April ²²17, 2003

Respectfully submitted,

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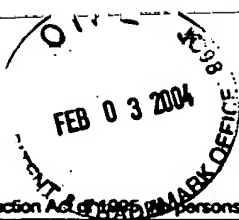
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Substitute for form 1449A/PTO				Complete If Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Application Number	10/022,722
				Filing Date	December 20, 2001
				First Named Inventor	Glen Hush
				Art Unit	2818
				Examiner Name	H. Hoang
Sheet	1	of	4	Attorney Docket Number	M4065.0481/P481

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (If known)			
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	AB	2002/0168820 App.	11/2002	Kozicki	
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				Attorney Docket Number	M4065.0481/P481
Sheet	2	of	4		

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		Country Code ³	Number ⁴ -Kind Code ⁵ (if known)				
	BA	JP	56126916	10/1981	Akira et al.		
	BB						

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		Application Number	10/022,722		
		Filing Date	December 20, 2001		
		First Named Inventor	Glen Hush		
		Group Art Unit	2818		
		Examiner Name	H. Hoang		
Sheet	4	of	4	Attorney Docket Number	M4065.0481/P481

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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	CP		
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